

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re application of: Dinkar Singh et. al.                    01/02/2004  
Serial No.:    Group No.:  
Filed: herewith    Examiner:  
**For: ENHANCED T-GATE STRUCTURE FOR MODULATION DOPED FIELD EFFECT  
TRANSISTORS**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**PRELIMINARY AMENDMENT**

## INTRODUCTORY COMMENTS

The attached application is a division of application Ser. No. 10/207,352 filed July 29, 2002. Copies of the original declaration and power of attorney, and an associate power of attorney are also filed.

Amendment to specification is on page 3, complete listing of all claims is on pages 4 to 6, page 7 contains remarks.